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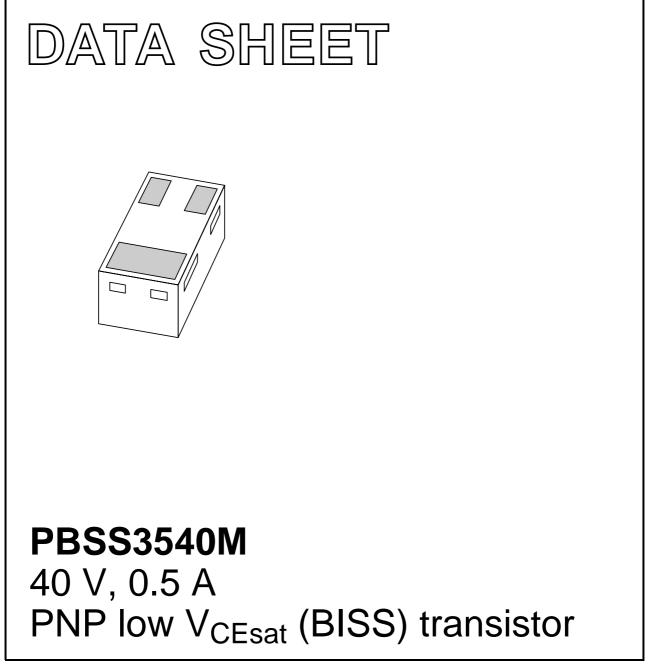
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Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS



Product data sheet

2003 Aug 12



40 V, 0.5 A PNP low V_{CEsat} (BISS) transistor

FEATURES

- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High efficiency leading to reduced heat generation
- Reduced printed-circuit board requirements.

APPLICATIONS

- Power management:
 - DC-DC converter
 - Supply line switching
 - Battery charger
 - LCD backlighting.
- Peripheral driver:
 - Driver in low supply voltage applications (e.g. lamps and LEDs).
 - Inductive load drivers (e.g. relays, buzzers and motors).

DESCRIPTION

Low V_{CEsat} PNP transistor in a SOT883 leadless ultra small plastic package. NPN complement: PBSS2540M.

MARKING

TYPE NUMBER	MARKING CODE		
PBSS3540M	DA		

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT	
V _{CEO}	collector-emitter voltage -40 V			
I _C	collector current (DC) –500		mA	
I _{CM}	peak collector current -1		А	
R _{CEsat}	equivalent on-resistance	iivalent on-resistance <700 mΩ		

PINNING

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	

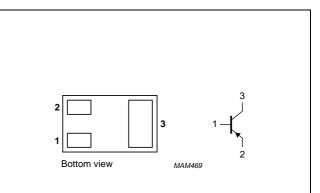


Fig.1 Simplified outline (SOT883) and symbol.

PBSS3540M

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	-40	V
V _{CEO}	collector-emitter voltage	open base	-	-40	V
V _{EBO}	emitter-base voltage	open collector	_	-6	V
I _C	collector current (DC)	notes 1 and 2	_	-500	mA
I _{CM}	peak collector current		-	-1	А
I _{BM}	peak base current		_	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$; notes 1 and 2	_	250	mW
		$T_{amb} \le 25 \ ^{\circ}C$; note 1 and 3	_	430	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Refer to SOT883 standard mounting conditions.
- 2. Device mounted on an FR4 printed-circuit board, single-sided copper, tinplated, standard footprint, with 60 μ m copper strip line.
- 3. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm².

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to	in free air; notes 1 and 2	500	K/W
	ambient	in free air; notes 1, 3 and 4	290	K/W

Notes

- 1. Refer to SOT883 standard mounting conditions.
- 2. Device mounted on an FR4 printed-circuit board, single-sided copper, tinplated, standard footprint, with 60 μ m copper strip line.
- 3. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm².
- 4. Operated under pulsed conditions: duty cycle $\delta \leq$ 20%, pulse width $t_p \leq$ 30 ms.

Soldering

Reflow soldering is the only recommended soldering method.

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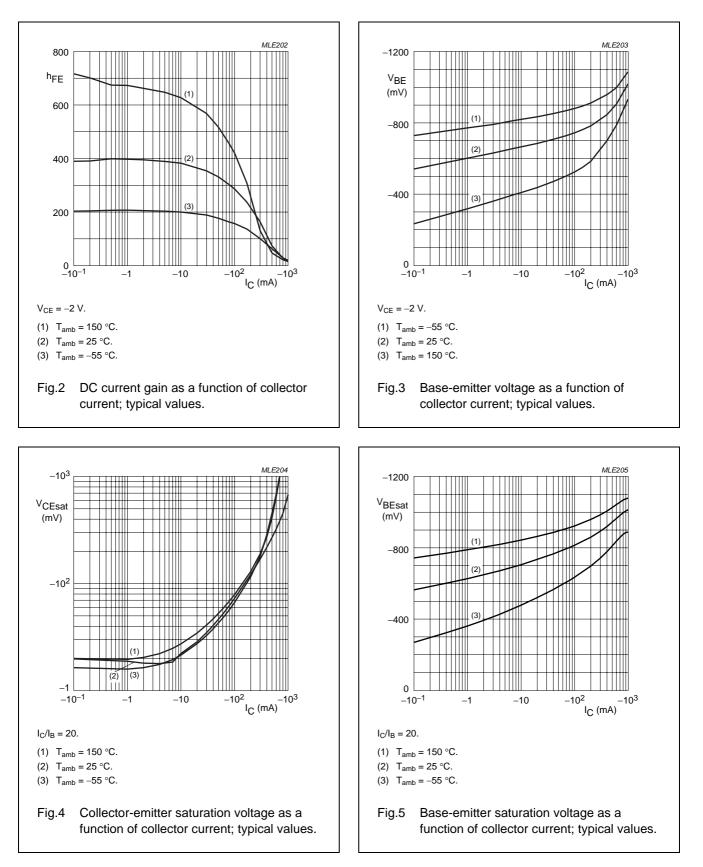
CHARACTERISTICS

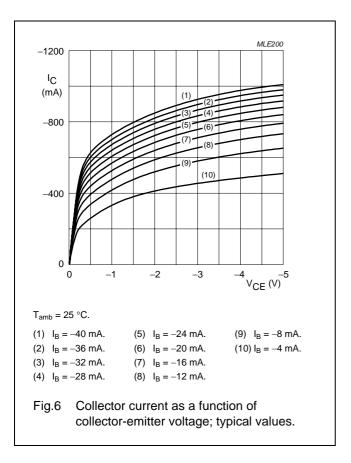
 T_{amb} = 25 °C unless otherwise specified.

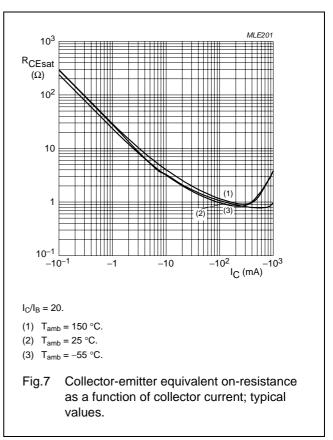
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -30 \text{ V}; \text{ I}_{E} = 0$	_	_	-100	nA
		$V_{CB} = -30 \text{ V}; I_E = 0; T_j = 150 ^{\circ}\text{C}$	_	_	-50	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0$	_	_	-100	nA
h _{FE}	DC current gain	$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -10 \text{ mA}$	200	-	-	
		$V_{CE} = -2 \text{ V}; I_C = -100 \text{ mA}; \text{ note } 1$	150	_	_	
		$V_{CE} = -2 \text{ V}; I_{C} = -500 \text{ mA}; \text{ note } 1$	40	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = -10 \text{ mA}; I_{B} = -0.5 \text{ mA}$	-	-	-50	mV
		$I_{C} = -100 \text{ mA}; I_{B} = -5 \text{ mA}$	-	-	-130	mV
		$I_{C} = -200 \text{ mA}; I_{B} = -10 \text{ mA}$	-	-	-200	mV
		$I_{C} = -500 \text{ mA}; I_{B} = -50 \text{ mA}; \text{ note } 1$	-	-	-350	mV
R _{CEsat}	equivalent on-resistance	$I_{C} = -500 \text{ mA}; I_{B} = -50 \text{ mA}; \text{ note 1}$	-	440	<700	mΩ
V _{BEsat}	base-emitter saturation voltage	$I_{C} = -500 \text{ mA}; I_{B} = -50 \text{ mA}; \text{ note 1}$	-	-	-1.2	V
V _{BEon}	base-emitter turn-on voltage	$V_{CE} = -2 \text{ V}; I_{C} = -100 \text{ mA}; \text{ note } 1$	-	-	-1.1	V
f _T	transition frequency	$I_{C} = -100 \text{ mA}; V_{CE} = -5 \text{ V};$ f = 100 MHz	100	300	-	MHz
Cc	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = I_e = 0; f = 1 \text{ MHz}$	-	_	10	pF

Note

1. Pulse test: $t_p \leq 300~\mu\text{s};~\delta \leq 0.02.$

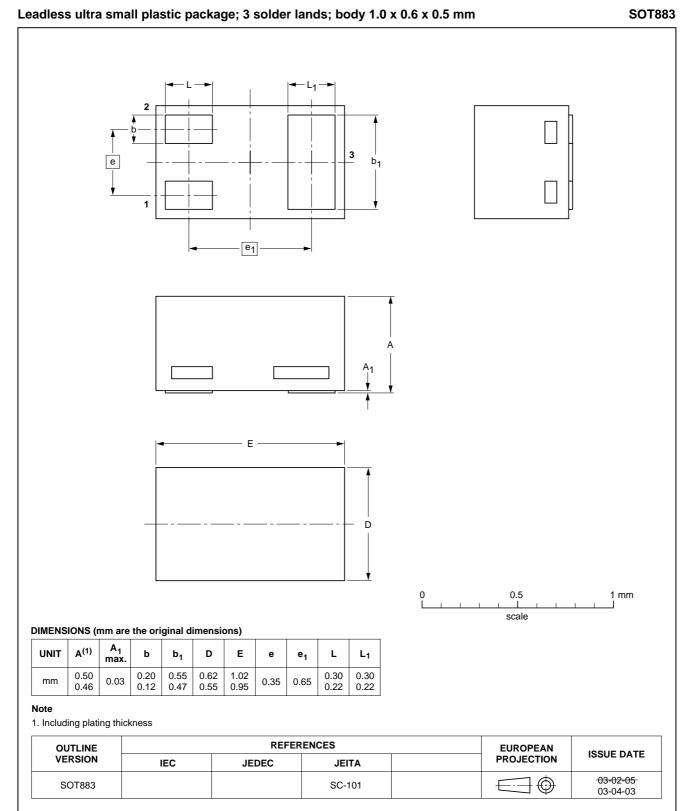






40 V, 0.5 A PNP low V_{CEsat} (BISS) transistor

PACKAGE OUTLINE



PBSS3540M

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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NXP Semiconductors

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Contact information

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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Printed in The Netherlands

613514/01/pp9

Date of release: 2003 Aug 12

Document order number: 9397 750 11561

